## 1. Scope

The present specifications shall apply to Sanken silicon diode, EN01Z.

## 2. Outline

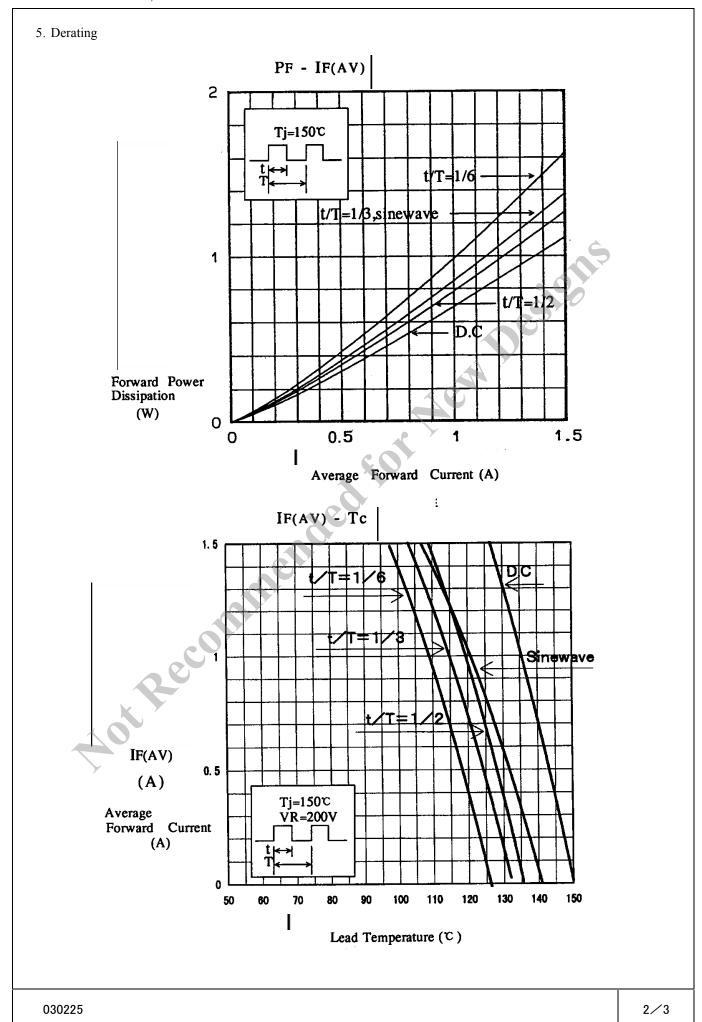
Туре	Silicon Rectifier Diode (Mesa type)		
Structure	Resin Molded Flammability: UL94V-0 (Equivalent)		
Applications	Pulse Rectification, etc		

## 3. Absolute maximum ratings

No.	Item	Symbol	Unit	Rating	Conditions
1	Transient Peak Reverse Voltage	$V_{RSM}$	V	200	
2	Peak Reverse Voltage	$V_{RM}$	V	200	
3	Average Forward Current	I <sub>F(AV)</sub>	A	1.5	Tl=107°C, Sinewave
4	Peak Surge Forward Current	$I_{FSM}$	A	50	10msec. Sinewave, one shot
5	Junction Temperature	$T_{j}$	°C	-40~+150	
6	Storage Temperature	$T_{stg}$	°C	-40~+150	

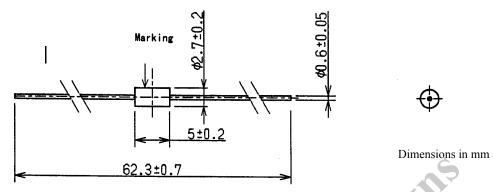
# 4. Electrical characteristics (Ta=25°C, unless otherwise specified)

No.	Item	Symbol	Unit	Value	Conditions
1	Forward Voltage Drop	$V_{\rm F}$	V	0.92 max.	I <sub>F</sub> =1.5A
2	Reverse Leakage Current	$I_R$	μΑ	10 max.	$V_R = V_{RM}$
3	Reverse Leakage Current Under High Temperature	$H \cdot I_R$	mA	2.0 max.	$V_R=V_{RM}$ , $T_j=150$ °C
4 4	Reverse Recovery Time	t rr1	ns	100 max.	@ IF=IRP=100mA 90% Recovery point
		t rr2	ns	50 max.	@ IF=100mA, IRP=200mA, 75% Recovery point
5	Thermal Resistance	Rth(j-l)	°C/W	20 max.	Between Junction and Lead



#### 6. Dimensions, inner structure and marking

#### 6-1 Dimensions refer

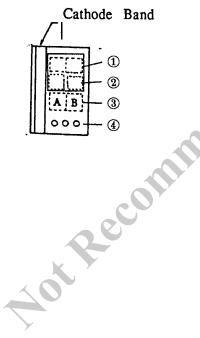


- \*1 The allowance position of body against the center of whole lead wire is 0.5mm (max.)
- \*2 The centric allowance of lead wire against center of physical body is 0.3mm (max.)
- \*3 The burr may exist up to 2mm from the body of lead.

## 6-2 Appearance

The body shall be clean and shall not bear any stain, rust or flaw. The color of the case will be black.

### 6-3 Marking



- ① Type number N0 as abbreviated as EN01
- ② Class number Z: 200V
- ③ Lot number 1
  - A: Year (Last digit of calendar year)
  - B: Month (From 1 to 9 for Jan. to sep.,

O for Oct., N for Nov., and D for Dec.)

4 Lot number 2 (ten days)

Ten days : • : First ten days, • · : Second ten days, ... : Third ten days